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Original papers (10)

[10] **Zhiping Bian**, Mitsuki Yoshimura, Ahrong Jeong, Haobo Li, Takashi Endo, Yasutaka Matsuo, Yusaku Magari, Hidekazu Tanaka, Hiromichi Ohta*, "Solid-State Electrochemical Thermal Switches with Large Thermal Conductivity Switching

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